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SEMICONDUCTOR



ESD



TVS



TSS



MOV



GDT



PLED

1.5SMCXXXA(CA)(MS)

Product specification

Features

- For surface mounted applications in order to optimize board space
- Low profile package
- Built-in strain relief
- Glass passivated junction
- Low inductance
- Excellent clamping capability
- 1500W peak pulse power capability at 10/1000µs waveform, repetition rate (duty cycle): 0.01%
- Fast response time
- Typical I_R less than 1µA above 12V
- High Temperature soldering: 260°C/10 seconds at terminals
- Plastic package has underwriters laboratory flammability 94V-0
- Meets MSL level 1, per J-STD-020


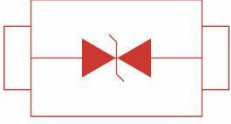


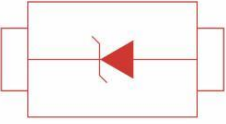

Mechanical Data

- Case: JEDEC DO-214AB. Molded plastic over glass passivated junction
- Terminal: Solder plated, solderable per MIL-STD-750, Method 2026
- Polarity: Color band denotes cathode except bi-directional models
- Standard Packaging: 16mm tape (EIA STD RS-481)
- Weight: 0.26g

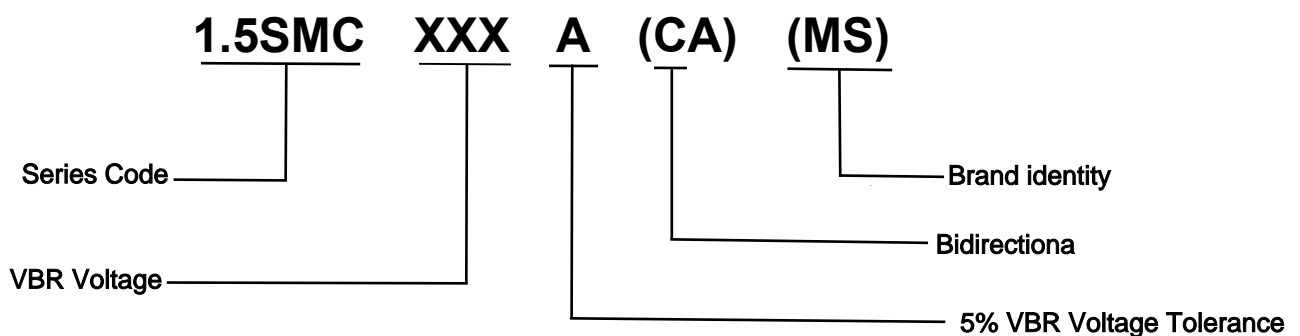
Applications

- I/O interface
- AC/DC power supply
- Low frequency signal transmission line (RS232, RS485, etc.)

Reference News

| PACKAGE OUTLINE | PIN CONFIGURATION | Marking Information |
|-------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
|  |  |  |
| Unipolar | | |
|  |  |  |
| Bipolar | | |

Part number code



Maximum Ratings and Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

| Rating | Symbol | Value | Units |
|-------------------------------------------------------------------------------------------------------------------|-----------------------------------|-------------|-------|
| Peak pulse power dissipation at 10/1000µs waveform (Note1, Note2, Fig.1) | P _{PPM} | 1500 | Watts |
| Peak pulse current of at 10/1000µs waveform (Note 1, Fig.3) | I _{PPM} | See Table | Amps |
| Steady state power dissipation at T _A =50°C (Fig.5) | P _{M(AV)} | 6.5 | Watts |
| Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load, (JEDEC Method) (Note3, Fig.6) | I _{FSM} | 200 | Amps |
| Operating junction and Storage Temperature Range. | T _J , T _{STG} | -55 to +150 | °C |
| Typical thermal resistance junction to lead | R _{θJL} | 15 | °C/W |
| Typical thermal resistance junction to ambient | R _{θJA} | 75 | °C/W |

Notes: 1. Non-repetitive current pulse, per Fig.3 and derated above T_A=25°C per Fig.2.

2. Mounted on 8.0mm×8.0mm copper pads to each terminal.

3. 8.3ms single half sine-wave, or equivalent square wave, duty cycle=4 pulses per minutes maximum.

Electrical Characteristics (T_A=25°C)

| Part Number | | Device Marking Code | | Reverse Stand-Off Voltage | Breakdown Voltage @I _T | Test Current | Maximum Clamping Voltage@I _{PP} | Peak Pulse Current | Reverse Leakage @V _{RWM} |
|----------------|---------------|---------------------|------|---------------------------|-----------------------------------|---------------------|------------------------------------------|---------------------|-----------------------------------|
| Unidirectional | Bidirectional | UNI | BI | V _{RWM} (V) | V _{BR} (V) | I _T (mA) | V _C (V) | I _{PP} (A) | I _R (µA) |
| 1.5SMC6.8A | 1.5SMC6.8CA | 6V8A | 6V8C | 5.80 | 6.45~7.14 | 10 | 10.5 | 144.8 | 1000 |
| 1.5SMC7.5A | 1.5SMC7.5CA | 7V5A | 7V5C | 6.40 | 7.13~7.88 | 10 | 11.3 | 134.5 | 500 |
| 1.5SMC8.2A | 1.5SMC8.2CA | 8V2A | 8V2C | 7.02 | 7.79~8.61 | 10 | 12.1 | 125.6 | 200 |
| 1.5SMC9.1A | 1.5SMC9.1CA | 9V1A | 9V1C | 7.78 | 8.65~9.55 | 1 | 13.4 | 113.4 | 50 |
| 1.5SMC10A | 1.5SMC10CA | 10A | 10C | 8.55 | 9.50~10.50 | 1 | 14.5 | 104.8 | 10 |
| 1.5SMC11A | 1.5SMC11CA | 11A | 11C | 9.40 | 10.50~11.60 | 1 | 15.6 | 97.4 | 5 |
| 1.5SMC12A | 1.5SMC12CA | 12A | 12C | 10.20 | 11.40~12.60 | 1 | 16.7 | 91.0 | 5 |
| 1.5SMC13A | 1.5SMC13CA | 13A | 13C | 11.10 | 12.40~13.70 | 1 | 18.2 | 83.5 | 1 |
| 1.5SMC15A | 1.5SMC15CA | 15A | 15C | 12.80 | 14.30~15.80 | 1 | 21.2 | 71.7 | 1 |
| 1.5SMC16A | 1.5SMC16CA | 16A | 16C | 13.60 | 15.20~16.80 | 1 | 22.5 | 67.6 | 1 |
| 1.5SMC18A | 1.5SMC18CA | 18A | 18C | 15.30 | 17.10~18.90 | 1 | 25.2 | 60.3 | 1 |
| 1.5SMC20A | 1.5SMC20CA | 20A | 20C | 17.10 | 19.00~21.00 | 1 | 27.7 | 54.9 | 1 |
| 1.5SMC22A | 1.5SMC22CA | 22A | 22C | 18.80 | 20.90~23.10 | 1 | 30.6 | 49.7 | 1 |
| 1.5SMC24A | 1.5SMC24CA | 24A | 24C | 20.50 | 22.80~25.20 | 1 | 33.2 | 45.8 | 1 |
| 1.5SMC27A | 1.5SMC27CA | 27A | 27C | 23.10 | 25.70~28.40 | 1 | 37.5 | 40.5 | 1 |
| 1.5SMC30A | 1.5SMC30CA | 30A | 30C | 25.60 | 28.50~31.50 | 1 | 41.4 | 36.7 | 1 |
| 1.5SMC33A | 1.5SMC33CA | 33A | 33C | 28.20 | 31.40~34.70 | 1 | 45.7 | 33.3 | 1 |
| 1.5SMC36A | 1.5SMC36CA | 36A | 36C | 30.80 | 34.20~37.80 | 1 | 49.9 | 30.5 | 1 |
| 1.5SMC39A | 1.5SMC39CA | 39A | 39C | 33.30 | 37.10~41.00 | 1 | 53.9 | 28.2 | 1 |

| Part Number | | Device Marking Code | | Reverse Stand-Off Voltage | Breakdown Voltage @ I_T | Test Current | Maximum Clamping Voltage@ I_{PP} | Peak Pulse Current | Reverse Leakage @ V_{RWM} |
|----------------|---------------|---------------------|------|---------------------------|---------------------------|--------------|------------------------------------|--------------------|-----------------------------|
| Unidirectional | Bidirectional | UNI | BI | $V_{RWM}(V)$ | $V_{BR}(V)$ | $I_T(mA)$ | $V_C(V)$ | $I_{PP}(A)$ | $I_R(\mu A)$ |
| 1.5SMC43A | 1.5SMC43CA | 43A | 43C | 36.80 | 40.90~45.20 | 1 | 59.3 | 25.6 | 1 |
| 1.5SMC47A | 1.5SMC47CA | 47A | 47C | 40.20 | 44.70~49.40 | 1 | 64.8 | 23.5 | 1 |
| 1.5SMC51A | 1.5SMC51CA | 51A | 51C | 43.60 | 48.50~53.60 | 1 | 70.1 | 21.7 | 1 |
| 1.5SMC56A | 1.5SMC56CA | 56A | 56C | 47.80 | 53.20~58.80 | 1 | 77.0 | 19.7 | 1 |
| 1.5SMC62A | 1.5SMC62CA | 62A | 62C | 53.00 | 58.90~65.10 | 1 | 85.0 | 17.9 | 1 |
| 1.5SMC68A | 1.5SMC68CA | 68A | 68C | 58.10 | 64.60~71.40 | 1 | 92.0 | 16.5 | 1 |
| 1.5SMC75A | 1.5SMC75CA | 75A | 75C | 64.10 | 71.30~78.80 | 1 | 103.0 | 14.8 | 1 |
| 1.5SMC82A | 1.5SMC82CA | 82A | 82C | 70.10 | 77.90~86.10 | 1 | 113.0 | 13.5 | 1 |
| 1.5SMC91A | 1.5SMC91CA | 91A | 91C | 77.80 | 86.50~95.50 | 1 | 125.0 | 12.2 | 1 |
| 1.5SMC100A | 1.5SMC100CA | 100A | 100C | 85.50 | 95.00~105.00 | 1 | 137.0 | 11.1 | 1 |
| 1.5SMC110A | 1.5SMC110CA | 110A | 110C | 94.00 | 105.00~116.00 | 1 | 152.0 | 10.0 | 1 |
| 1.5SMC120A | 1.5SMC120CA | 120A | 120C | 102.00 | 114.00~126.00 | 1 | 165.0 | 9.2 | 1 |
| 1.5SMC130A | 1.5SMC130CA | 130A | 130C | 111.00 | 124.00~137.00 | 1 | 179.0 | 8.5 | 1 |
| 1.5SMC150A | 1.5SMC150CA | 150A | 150C | 128.00 | 143.00~158.00 | 1 | 207.0 | 7.3 | 1 |
| 1.5SMC160A | 1.5SMC160CA | 160A | 160C | 136.00 | 152.00~168.00 | 1 | 219.0 | 6.9 | 1 |
| 1.5SMC170A | 1.5SMC170CA | 170A | 170C | 145.00 | 162.00~179.00 | 1 | 234.0 | 6.5 | 1 |
| 1.5SMC180A | 1.5SMC180CA | 180A | 180C | 154.00 | 171.00~189.00 | 1 | 246.0 | 6.2 | 1 |
| 1.5SMC200A | 1.5SMC200CA | 200A | 200C | 171.00 | 190.00~210.00 | 1 | 274.0 | 5.5 | 1 |
| 1.5SMC220A | 1.5SMC220CA | 220A | 220C | 185.00 | 209.00~231.00 | 1 | 328.0 | 4.6 | 1 |
| 1.5SMC250A | 1.5SMC250CA | 250A | 250C | 214.00 | 237.00~263.00 | 1 | 344.0 | 4.4 | 1 |
| 1.5SMC300A | 1.5SMC300CA | 300A | 300C | 256.00 | 285.00~315.00 | 1 | 414.0 | 3.7 | 1 |
| 1.5SMC350A | 1.5SMC350CA | 350A | 350C | 300.00 | 332.00~368.00 | 1 | 482.0 | 3.2 | 1 |
| 1.5SMC400A | 1.5SMC400CA | 400A | 400C | 342.00 | 380.00~420.00 | 1 | 548.0 | 2.8 | 1 |
| 1.5SMC440A | 1.5SMC440CA | 440A | 440C | 376.00 | 418.00~462.00 | 1 | 602.0 | 2.5 | 1 |
| 1.5SMC480A | 1.5SMC480CA | 480A | 480C | 408.00 | 456.00~504.00 | 1 | 658.0 | 2.3 | 1 |
| 1.5SMC510A | 1.5SMC510CA | 510A | 510C | 434.00 | 485.00~535.00 | 1 | 698.0 | 2.1 | 1 |
| 1.5SMC530A | 1.5SMC530CA | 530A | 530C | 450.00 | 503.50~556.50 | 1 | 725.0 | 2.1 | 1 |
| 1.5SMC540A | 1.5SMC540CA | 540A | 540C | 459.00 | 513.00~567.00 | 1 | 740.0 | 2.0 | 1 |
| 1.5SMC550A | 1.5SMC550CA | 550A | 550C | 467.00 | 522.50~577.50 | 1 | 760.0 | 2.0 | 1 |

Ratings and Characteristic Curves ($T_A=25^\circ\text{C}$ unless otherwise noted)

Figure 1. Peak Pulse Power Rating Curve

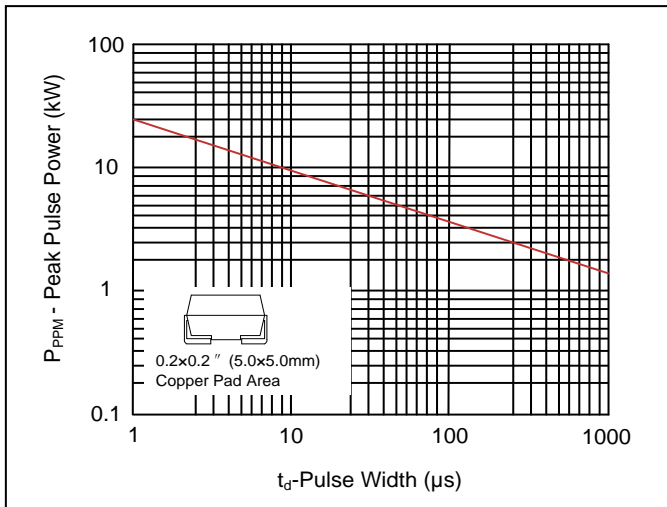


Figure 2. Pulse Derating Curve

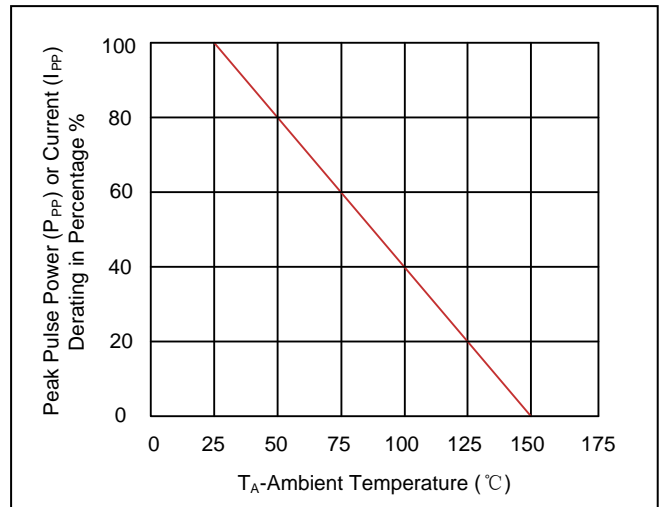


Figure 3. Pulse Waveform

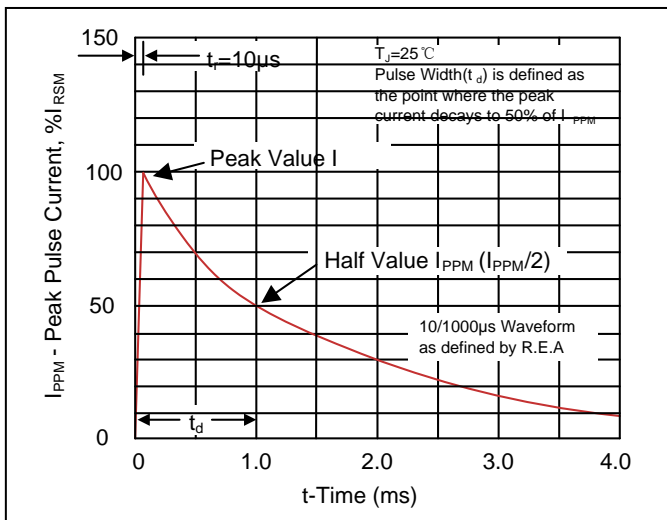


Figure 4. Typical Junction Capacitance

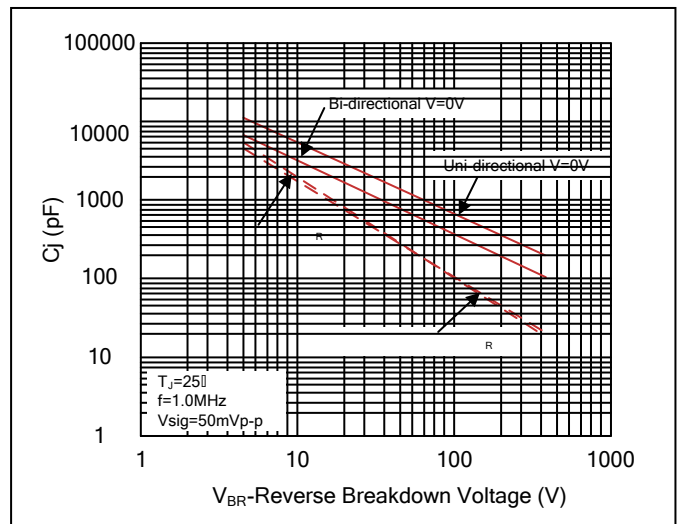


Figure 5. Steady State Power Dissipation Derating Curve

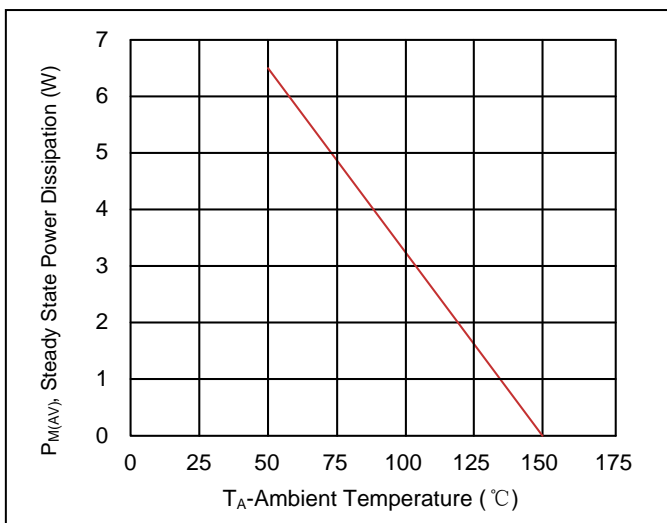
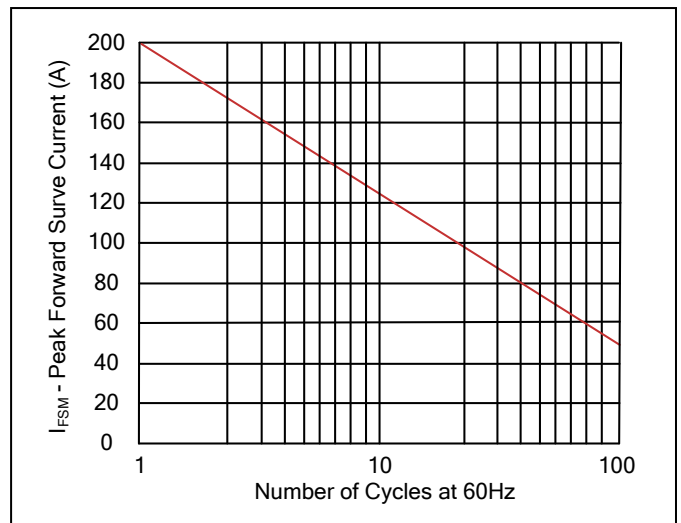
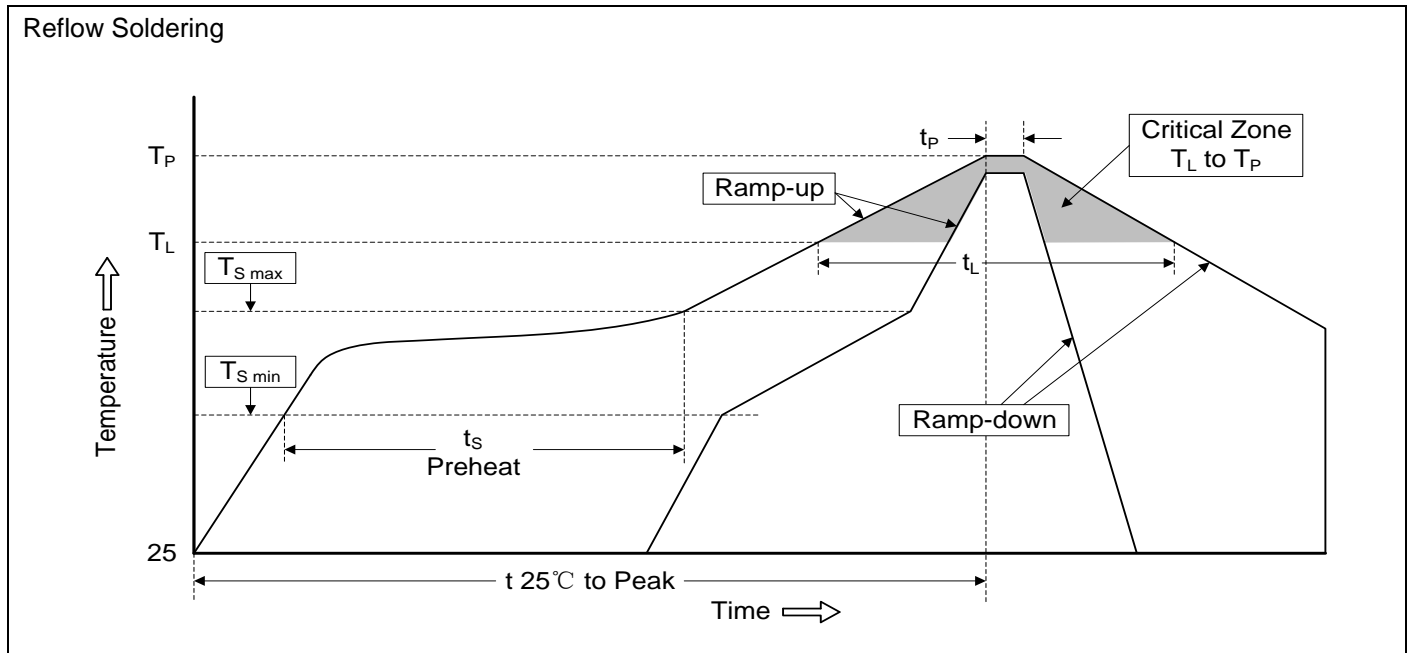


Figure 6. Maximum Non-Repetitive Forward Surge Current Uni-Directional Only



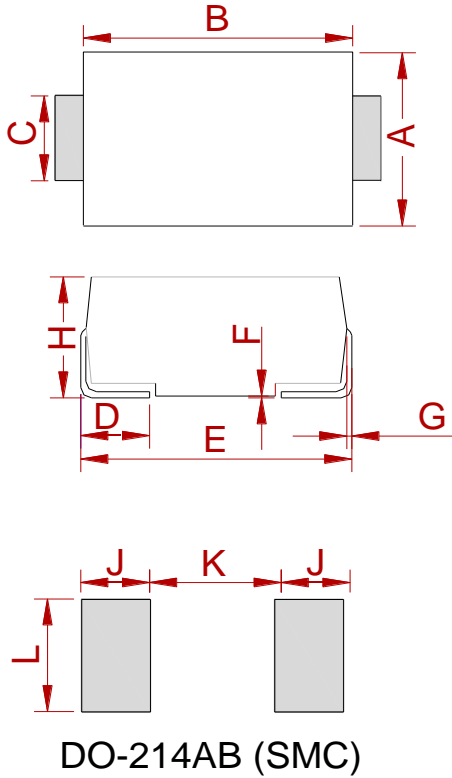
Recommended Soldering Conditions



Recommended Conditions

| Profile Feature | Pb-Free Assembly |
|-------------------------------------------------------------------------------------------------------------------|----------------------------------|
| Average ramp-up rate (T_L to T_P) | 3°C/second max. |
| Preheat -Temperature Min ($T_{S\ min}$) -Temperature Max ($T_{S\ max}$) -Time (min to max) (t_s) | 150°C 200°C 60-180 seconds |
| $T_{S\ max}$ to T_L -Ramp-up Rate | 3°C/second max. |
| Time maintained above: -Temperature (T_L) -Time (t_L) | 217°C 60-150 seconds |
| Peak Temperature (T_P) | 260°C |
| Time within 5°C of actual Peak Temperature (t_p) | 20-40 seconds |
| Ramp-down Rate | 6°C/second max. |
| Time 25°C to Peak Temperature | 8 minutes max. |

PACKAGE MECHANICAL DATA



| Ref. | Dimensions | | | |
|------|-------------|-------|--------|-------|
| | Millimeters | | Inches | |
| | Min. | Max. | Min. | Max. |
| A | 5.75 | 6.25 | 0.226 | 0.246 |
| B | 6.90 | 7.40 | 0.272 | 0.291 |
| C | 2.75 | 3.25 | 0.108 | 0.128 |
| D | 0.95 | 1.52 | 0.037 | 0.060 |
| E | 7.70 | 8.20 | 0.303 | 0.323 |
| F | 0.051 | 0.203 | 0.002 | 0.008 |
| G | 0.15 | 0.31 | 0.006 | 0.012 |
| H | 2.15 | 2.62 | 0.085 | 0.103 |
| J | 2.40 | | 0.094 | |
| K | | 4.20 | | 0.165 |
| L | 3.30 | | 0.130 | |

REEL SPECIFICATION

| P/N | PKG | QTY |
|--------------------|-----|------|
| 1.5SMCXXXA(CA)(MS) | SMC | 3000 |

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